

MITSUBISHI IGBT MODULES
CM400DU-12H
 HIGH POWER SWITCHING USE
 INSULATED TYPE

CM400DU-12H



- IC 400A
- VCES 600V
- Insulated Type
- 2-elements in a pack
- UL Recognized

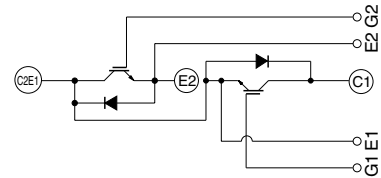
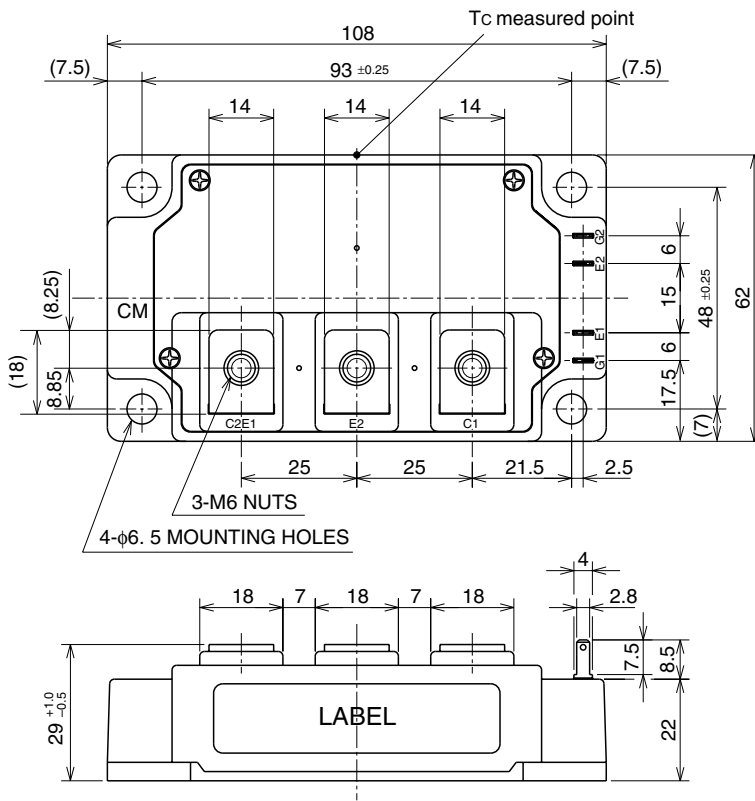
Yellow Card No. E80276
 File No. E80271

APPLICATION

UPS, NC machine, AC-Drive control, Servo, Welders

OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



CIRCUIT DIAGRAM

CM400DU-12H

**HIGH POWER SWITCHING USE
INSULATED TYPE**

MAXIMUM RATINGS (T_j = 25°C, unless otherwise specified)

Symbol	Item	Conditions	Ratings	Unit
V _{CE}	Collector-emitter voltage	V _{GE} = 0V	600	V
V _{GE}	Gate-emitter voltage	V _{CE} = 0V	±20	V
I _C	Collector current	T _C = 25°C	400	A
I _{CM}		Pulse (Note 1)	800	A
I _E (Note 2)	Emitter current	T _C = 25°C	400	A
I _{EM} (Note 2)		Pulse (Note 1)	800	A
P _C (Note 3)	Maximum collector dissipation	T _C = 25°C	1130	W
T _j	Junction temperature	—	-40 ~ +150	°C
T _{stg}	Storage temperature	—	-40 ~ +125	°C
V _{iso}	Isolation voltage	Charged part to base plate, f = 60Hz, AC 1 minute	2500	V _{rms}
—	Mounting torque	Main terminals M6 screw	3.5 ~ 4.5	N·m
		Mounting M6 screw	3.5 ~ 4.5	N·m
—	Weight	Typical value	400	g

ELECTRICAL CHARACTERISTICS (T_j = 25°C, unless otherwise specified)

Symbol	Item	Test Conditions	Limits			Unit	
			Min	Typ	Max		
I _{CES}	Collector cutoff current	V _{CE} = V _{CE} , V _{GE} = 0V	—	—	1	mA	
V _{GE(th)}	Gate-emitter threshold voltage	I _C = 40mA, V _{CE} = 10V	4.5	6	7.5	V	
I _{GES}	Gate-leakage current	±V _{GE} = V _{GES} , V _{CE} = 0V	—	—	0.5	μA	
V _{CE(sat)}	Collector-emitter saturation voltage	I _C = 400A, V _{GE} = 15V (Note 4)	T _j = 25°C	—	2.4	3.0	V
			T _j = 125°C	—	2.6	—	
C _{ies}	Input capacitance	V _{CE} = 10V	—	—	35.2	nF	
C _{oes}	Output capacitance	V _{GE} = 0V	—	—	19.2	nF	
C _{res}	Reverse transfer capacitance	—	—	—	5.2	nF	
Q _G	Total gate charge	V _{CC} = 300V, I _C = 400A, V _{GE} = 15V	—	800	—	nC	
t _{d(on)}	Turn-on delay time	V _{CC} = 300V, I _C = 400A	—	—	250	ns	
t _r	Turn-on rise time	V _{GE} = ±15V	—	—	600	ns	
t _{d(off)}	Turn-off delay time	R _G = 1.6Ω	—	—	350	ns	
t _f	Turn-off fall time	Resistive load	—	—	300	ns	
V _{EC} (Note 2)	Emitter-collector voltage	I _E = 400A, V _{GE} = 0V	—	—	2.6	V	
t _{rr} (Note 2)	Reverse recovery time	I _E = 400A,	—	—	160	ns	
Q _{rr} (Note 2)	Reverse recovery charge	die / dt = -800A / μs	—	0.96	—	μC	
R _{th(j-c)Q}	Thermal resistance (Note 5)	Junction to case, IGBT part (Per 1/2 module)	—	—	0.11	K/W	
R _{th(j-c)R}		Junction to case, FWDi part (Per 1/2 module)	—	—	0.18	K/W	
R _{th(c-f)}	Contact thermal resistance	Case to heat sink, conductive grease applied (Per 1/2 module) (Note 6)	—	0.04	—	K/W	

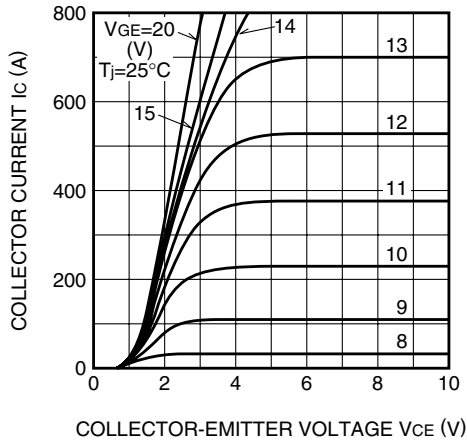
- Note 1. Pulse width and repetition rate should be such that the device junction temperature (T_j) does not exceed T_{jmax} rating.
 2. I_E, I_{EM}, V_{EC}, t_{rr}, Q_{rr} & die/dt represent characteristics of the anti-parallel, emitter-collector free-wheel diode.
 3. Junction temperature (T_j) should not increase beyond 150°C.
 4. Pulse width and repetition rate should be such as to cause negligible temperature rise.
 5. Case temperature (T_C) measured point is shown in page OUTLINE DRAWING.
 6. Typical value is measured by using thermally conductive grease of λ = 0.9[W/(m · K)].

CM400DU-12H

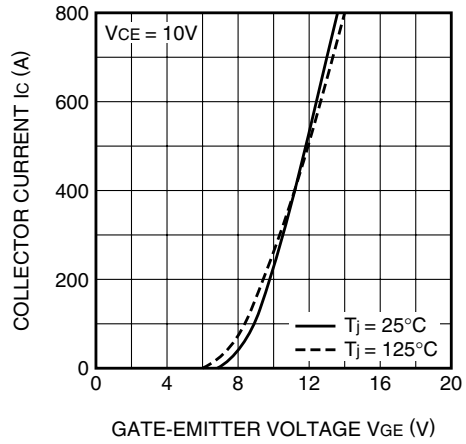
HIGH POWER SWITCHING USE
INSULATED TYPE

PERFORMANCE CURVES

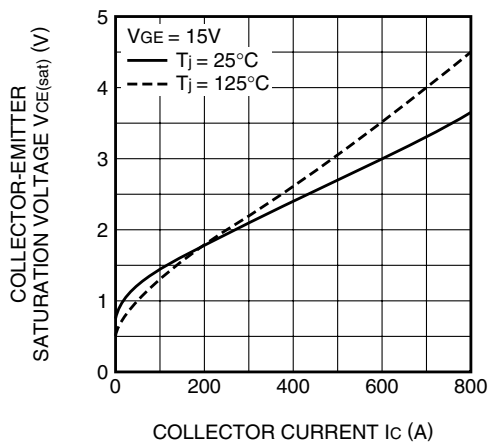
OUTPUT CHARACTERISTICS (TYPICAL)



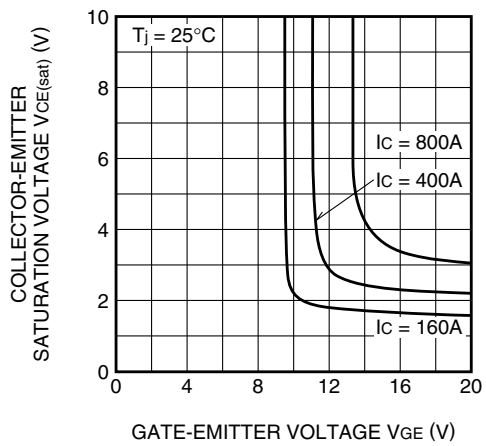
TRANSFER CHARACTERISTICS (TYPICAL)



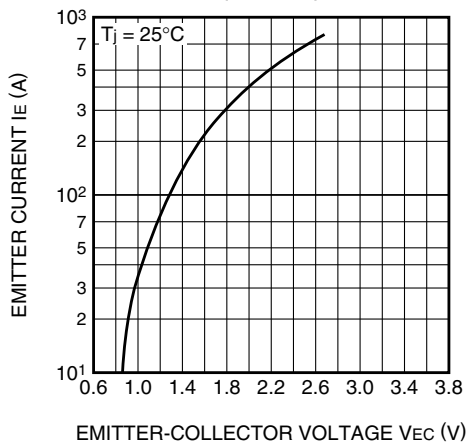
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



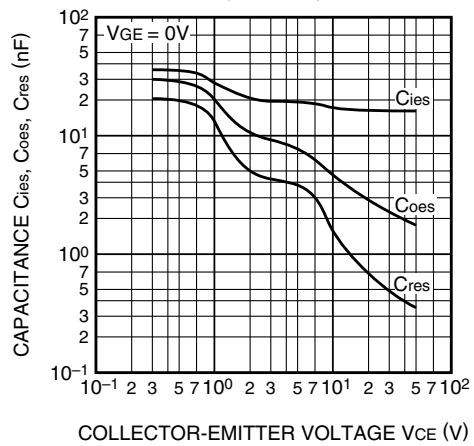
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



FREE-WHEEL DIODE FORWARD CHARACTERISTICS (TYPICAL)



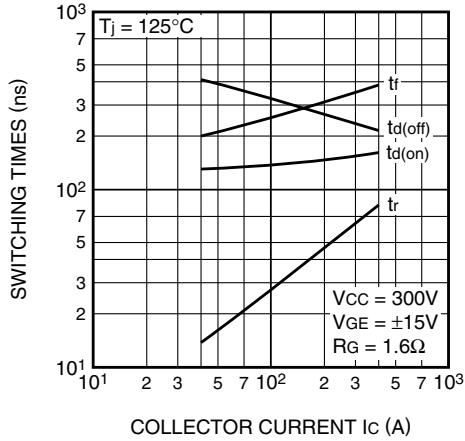
CAPACITANCE CHARACTERISTICS (TYPICAL)



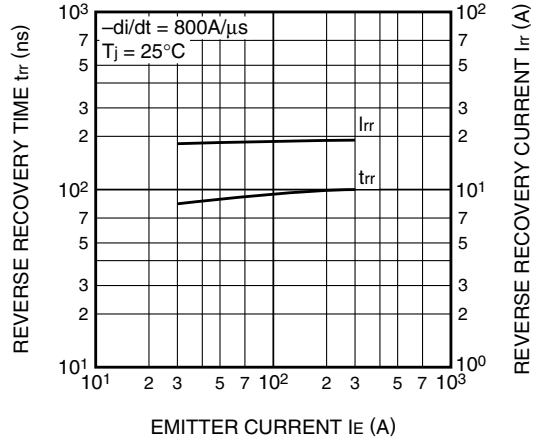
CM400DU-12H

HIGH POWER SWITCHING USE
INSULATED TYPE

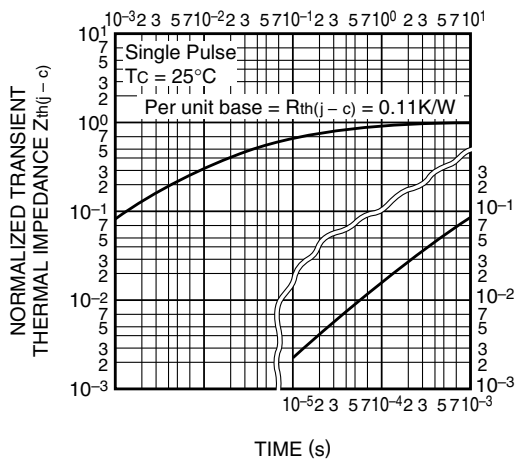
HALF-BRIDGE
SWITCHING TIME CHARACTERISTICS
(TYPICAL)



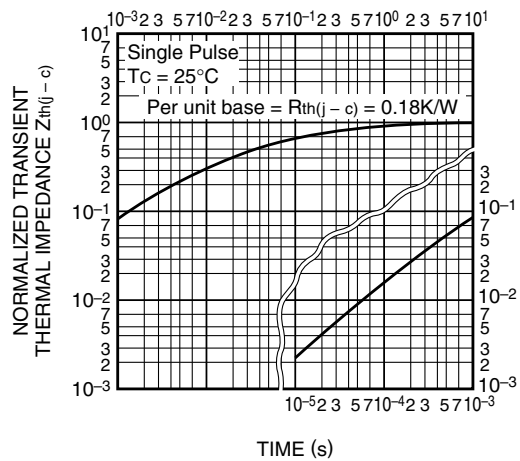
REVERSE RECOVERY CHARACTERISTICS
OF FREE-WHEEL DIODE
(TYPICAL)



TRANSIENT THERMAL
IMPEDANCE CHARACTERISTICS
(IGBT part)



TRANSIENT THERMAL
IMPEDANCE CHARACTERISTICS
(FWDi part)



GATE CHARGE CHARACTERISTICS
(TYPICAL)

